LP3893 3A Fast-Response Ultra Low Dropout Linear Regulators

Check for Samples: LP3893

FEATURES

- **Ultra Low Dropout Voltage (270 mV at 3A typ)**
- **Low Ground Pin Current**
- **Load Regulation of 0.04%/A**
- **60 nA Typical Quiescent Current in Shutdown**
- **1.5% Output Accuracy (25°C)**
- **TO-220, DDPAK/TO-263 Packages**
- **Over Temperature/Over Current Protection**
- **−40°C to +125°C Junction Temperature Range**

APPLICATIONS

- **DSP Power Supplies**
- **Server Core and I/O Supplies**
- **Linear Power Supplies for PC Add-in-Cards**
- **Set-Top Box Power Supplies**
- **Microprocessor Power Supplies**
- **High Efficiency Linear Power Supplies**
- **SMPS Post-Regulators**

DESCRIPTION

The LP3893 is a high-current, fast-response regulator which can maintain output voltage regulation with minimum input to output voltage drop. Fabricated on a CMOS process, the device operates from two input voltages: Vbias provides voltage to drive the gate of the N-MOS power transistor, while Vin is the input voltage which supplies power to the load. The use of an external bias rail allows the part to operate from ultra low Vin voltages. Unlike bipolar regulators, the CMOS architecture consumes extremely low quiescent current at any output load current. The use of an N-MOS power transistor results in wide bandwidth, yet minimum external capacitance is required to maintain loop stability.

The fast transient response of these devices makes them suitable for use in powering DSP, Microcontroller Core voltages and Switch Mode Power Supply post regulators. The parts are available in TO-220 and DDPAK/TO-263 packages.

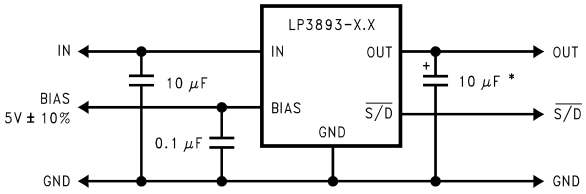
Dropout Voltage: 270 mV (typ) at 3A load current.

Ground Pin Current: 3 mA (typ) at full load.

Shutdown Current: 60 nA (typ) when S/D pin is low.

Precision Output Voltage: 1.5% room temperature accuracy.

TYPICAL APPLICATION CIRCUIT



At least 10 µF of input and output capacitance is required for stability.
*Tantalum capacitors are recommended. Aluminum electrolytic capacitors may be used for restricted temperature range. See application hints.

CONNECTION DIAGRAM

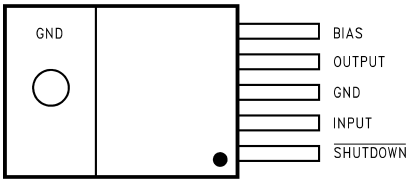


Figure 1. TO-220, Top View

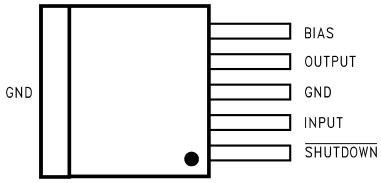


Figure 2. DDPAK/TO-263, Top View

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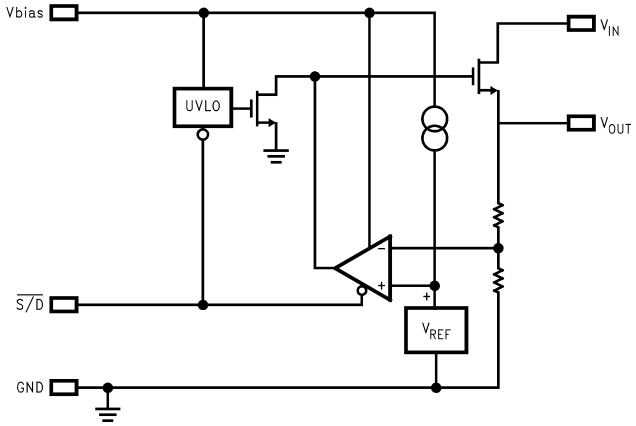
These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS (1)

If Military/Aerospace specified devices are required, contact the Texas Instruments Sales Office/Distributors for availability and specifications.

	VALUE / UNITS
Storage Temperature Range	−65°C to +150°C
Lead Temp. (Soldering, 5 seconds)	260°C
ESD Rating Human Body Model (2) Machine Model (3)	 2 kV 200V
Power Dissipation (4)	Internally Limited
V_{IN} Supply Voltage (Survival)	−0.3V to +6V
V_{BIAS} Supply Voltage (Survival)	−0.3V to +7V
Shutdown Input Voltage (Survival)	−0.3V to +7V
I_{OUT} (Survival)	Internally Limited
Output Voltage (Survival)	−0.3V to +6V
Junction Temperature	−40°C to +150°C

(1) Absolute maximum ratings indicate limits beyond which damage to the component may occur. Operating ratings indicate conditions for which the device is intended to be functional, but do **not** ensure specific performance limits. For specifications, see Electrical Characteristics. Specifications do not apply when operating the device outside of its rated operating conditions.
(2) The human body model is a 100 pF capacitor discharged through a 1.5k resistor into each pin.
(3) The machine model is a 220 pF capacitor discharged directly into each pin. The machine model ESD rating of pin 5 is 100V.
(4) At elevated temperatures, device power dissipation must be derated based on package thermal resistance and heatsink thermal values. θ_{J-A} for TO-220 devices is 65°C/W if no heatsink is used. If the TO-220 device is attached to a heatsink, a θ_{J-S} value of 4°C/W can be assumed. θ_{J-A} for DDPAK/TO-263 devices is approximately 40°C/W if soldered down to a copper plane which is at least 1.5 square inches in area. If power dissipation causes the junction temperature to exceed specified limits, the device will go into thermal shutdown.

RECOMMENDED OPERATING CONDITIONS

	VALUE / UNITS
V_{IN}	(V_{OUT} + V_{DO}) to 5.5V
Shutdown	0 to +6V
I_{OUT}	3A
Junction Temperature	−40°C to +125°C
V_{BIAS}	4.5V to 6V

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ELECTRICAL CHARACTERISTICS

Limits in standard typeface are for T_J = 25°C, and limits in **boldface type** apply over the full operating temperature range. Unless otherwise specified: $V_{IN} = V_O(NOM) + 1V$, V_{BIAS} = 4.5V, I_L = 10 mA, $C_{IN} = C_{OUT}$ =10 µF, $V_{S/D} = V_{BIAS}$.

Symbol	Parameter	Conditions	Typical (1)	MIN (2)	MAX (2)	Units
V_O	Output Voltage Tolerance	10 mA ≤ I_L ≤ 3A $V_O(NOM) + 1V \le V_{IN} \le 5.5V$ $4.5V \le V_{BIAS} \le 6V$	1.216	1.198 **1.186**	1.234 **1.246**	V
			1.5	1.478 **1.455**	1.522 **1.545**	
			1.8	1.773 **1.746**	1.827 **1.854**	
$\Delta V_O/\Delta V_{IN}$	Output Voltage Line Regulation (3)	$V_O(NOM) + 1V \le V_{IN} \le 5.5V$	0.01			%/V
$\Delta V_O/\Delta I_L$	Output Voltage Load Regulation (4)	10 mA ≤ I_L ≤ 3A	0.04 **0.06**			%/A
V_{DO}	Dropout Voltage (5)	I_L = 3A	270		650 **1000**	mV
$I_Q(V_{IN})$	Quiescent Current Drawn from V_{IN} Supply	10 mA ≤ I_L ≤ 3A	3		7 **8**	mA
		$V_{\overline{S/D}} \le 0.3V$	0.03		1 **30**	µA
$I_Q(V_{BIAS})$	Quiescent Current Drawn from V_{BIAS} Supply	10 mA ≤ I_L ≤ 3A	1		2 **3**	mA
		$V_{\overline{S/D}} \le 0.3V$	0.03		1 **30**	µA
I_{SC}	Short-Circuit Current	V_{OUT} = 0V	6			A
Shutdown Input						
V_{SDT}	Output Turn-off Threshold	Output = ON	0.7	**1.3**		V
		Output = OFF	0.7		**0.3**	
Td (OFF)	Turn-OFF Delay	R_{LOAD} X C_{OUT} << Td (OFF)	20			µs
Td (ON)	Turn-ON Delay	R_{LOAD} X C_{OUT} << Td (ON)	15			
$I_{\overline{S/D}}$	$\overline{S/D}$ Input Current	$V_{\overline{S/D}}$ =1.3V	1			µA
		$V_{\overline{S/D}} \le 0.3V$	−1			
AC Parameters						
PSRR (V_{IN})	Ripple Rejection for V_{IN} Input Voltage	$V_{IN} = V_{OUT}$ +1V, f = 120 Hz	80			dB
		$V_{IN} = V_{OUT}$ + 1V, f = 1 kHz	65			
PSRR (V_{BIAS})	Ripple Rejection for V_{BIAS} Voltage	$V_{BIAS} = V_{OUT}$ + 3V, f = 120 Hz	70			
		$V_{BIAS} = V_{OUT}$ + 3V, f = 1 kHz	65			
	Output Noise Density	f = 120 Hz	1			µV/root−Hz
e_n	Output Noise Voltage	BW = 10 Hz − 100 kHz, V_{OUT} = 1.8V	150			µV (rms)
		BW = 300 Hz − 300 kHz, V_{OUT} = 1.8V	90			

(1) Typical numbers represent the most likely parametric norm for 25°C operation.
(2) Limits are specified through testing, statistical correlation, or design.
(3) Output voltage line regulation is defined as the change in output voltage from nominal value resulting from a change in input voltage.
(4) Output voltage load regulation is defined as the change in output voltage from nominal value as the load current increases from no load to full load.
(5) Dropout voltage is defined as the minimum input to output differential required to maintain the output with 2% of nominal value.

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TYPICAL PERFORMANCE CHARACTERISTICS

Unless otherwise specified: T_j = 25°C, C_{OUT} = 10 µF, Cin = 10 µF, $\overline{S/D}$ pin is tied to V_{BIAS}, V_{IN} = 2.2V, V_{OUT} = 1.8V.

I_{GND} vs V_{SD}

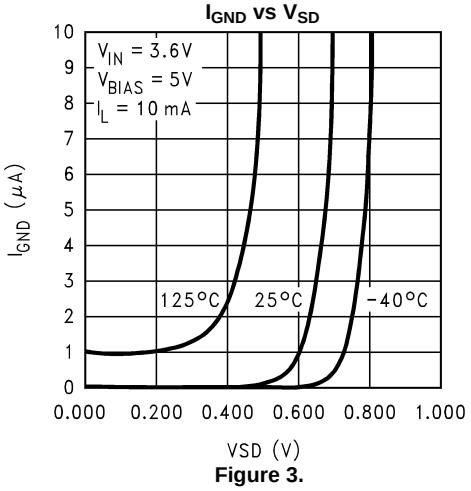

Figure 3.

V_{OUT} vs Temperature

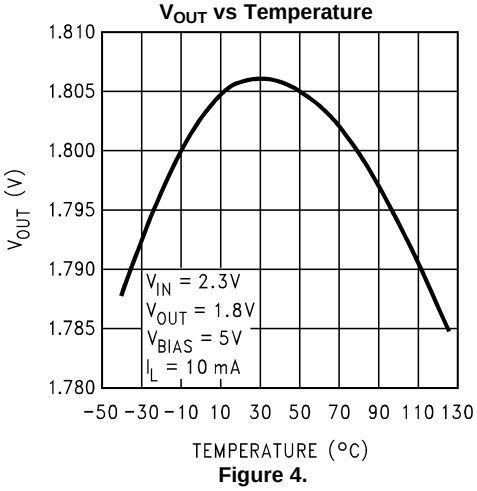

Figure 4.

DC Load Regulation

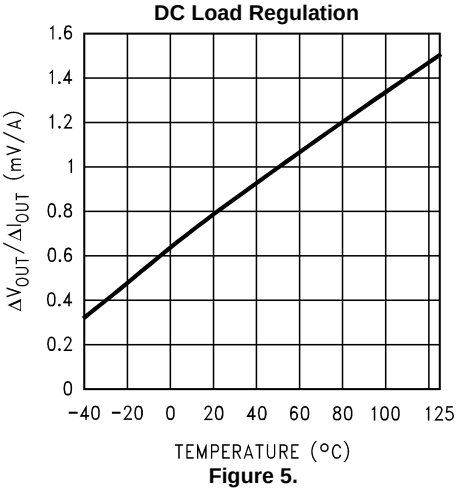

Figure 5.

Line Regulation vs V_{IN}

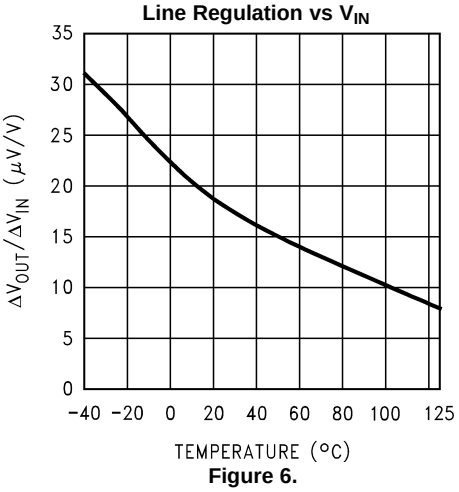

Figure 6.

Line Regulation vs V_{BIAS}

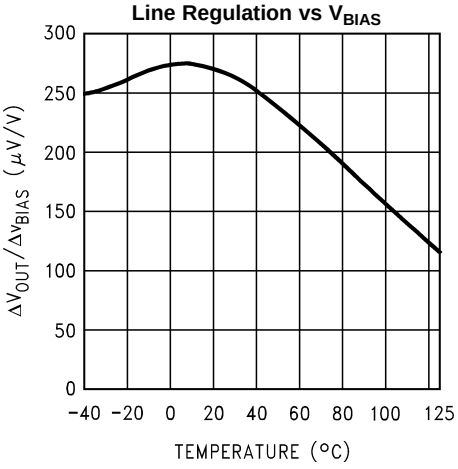

Figure 7.

I_{BIAS} vs I_L

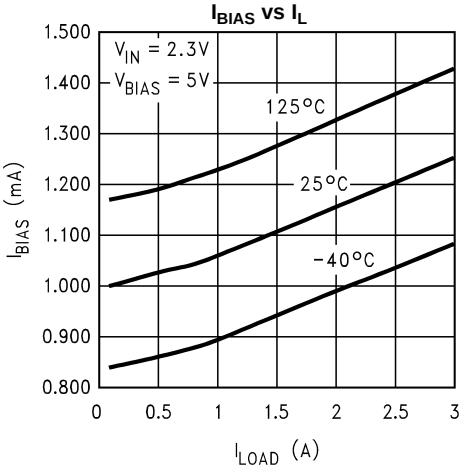

Figure 8.

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TYPICAL PERFORMANCE CHARACTERISTICS (continued)

Unless otherwise specified: T_j = 25°C, C_{OUT} = 10 µF, Cin = 10 µF, $\overline{S/D}$ pin is tied to V_{BIAS}, V_{IN} = 2.2V, V_{OUT} = 1.8V.

I_{LOAD} vs Dropout Voltage

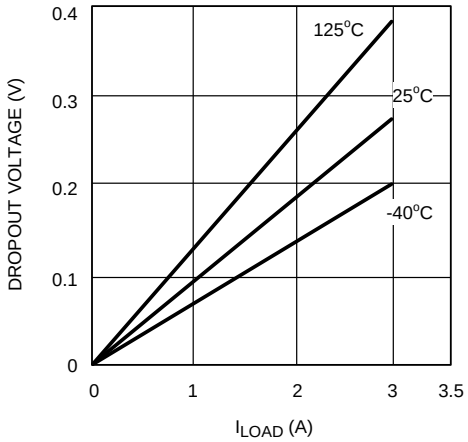

Figure 9.

I_{GND} vs V_{SD}

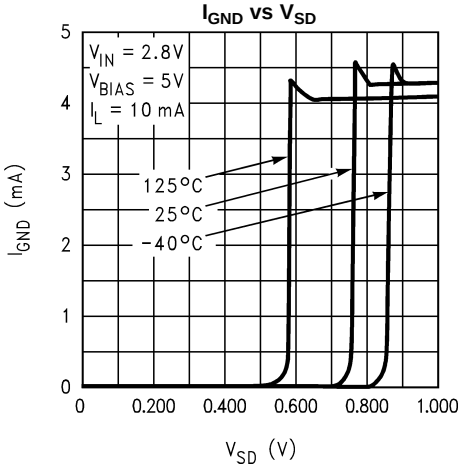

Figure 10.

Noise Measurement

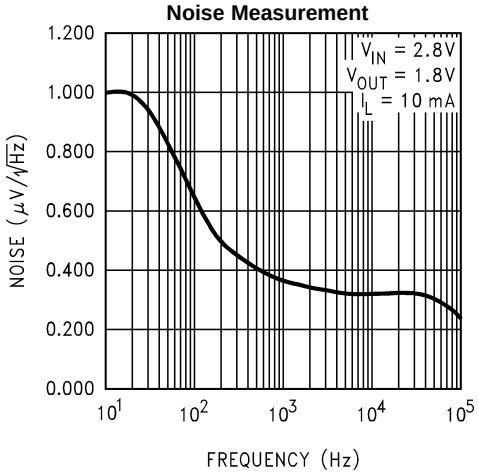

Figure 11.

V_{OUT}Startup Waveform

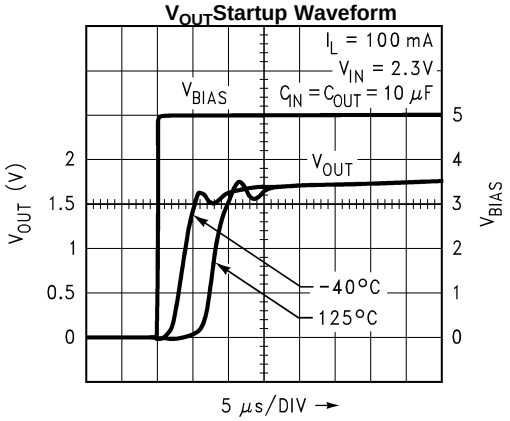

Figure 12.

V_{OUT}Startup Waveform

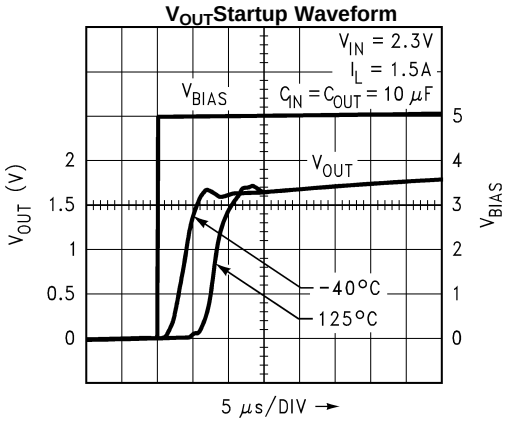

Figure 13.

V_{OUT}Startup Waveform

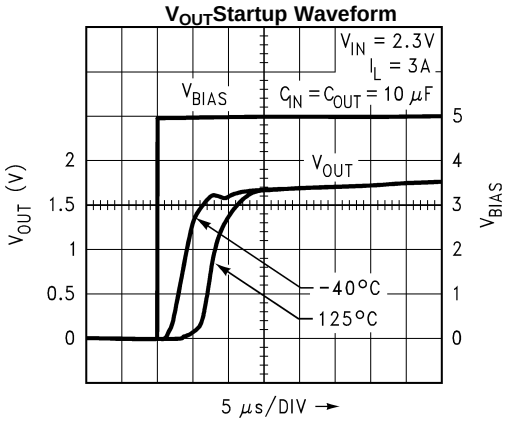

Figure 14.

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TYPICAL PERFORMANCE CHARACTERISTICS (continued)

Unless otherwise specified: T_j = 25°C, C_{OUT} = 10 µF, Cin = 10 µF, $\overline{S/D}$ pin is tied to V_{BIAS}, V_{IN} = 2.2V, V_{OUT} = 1.8V.

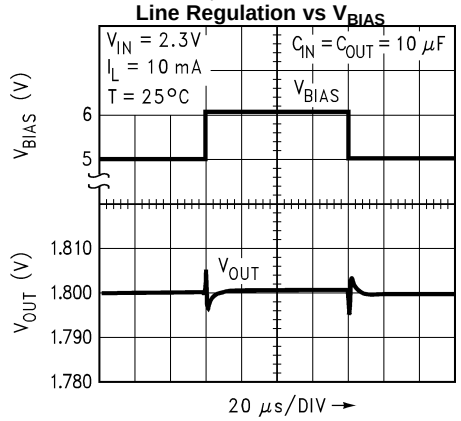

Figure 15.

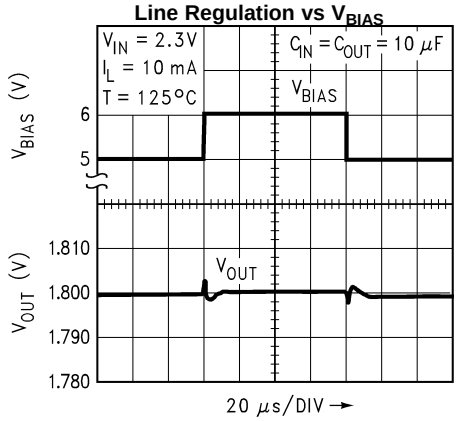

Figure 16.

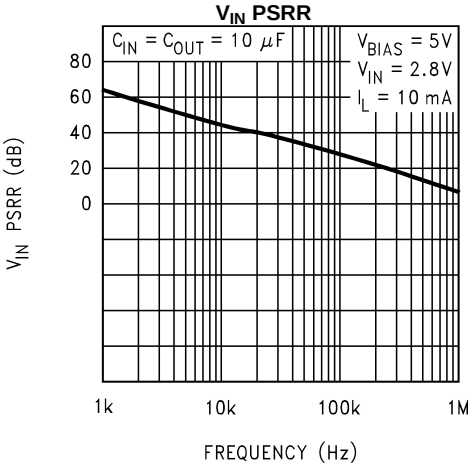

Figure 17.

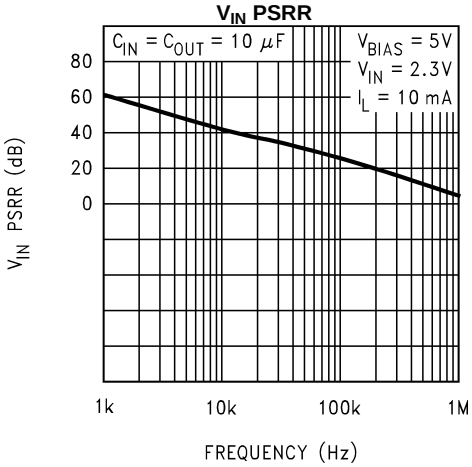

Figure 18.

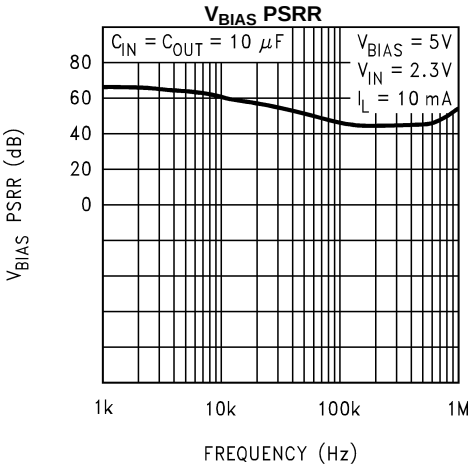

Figure 19.

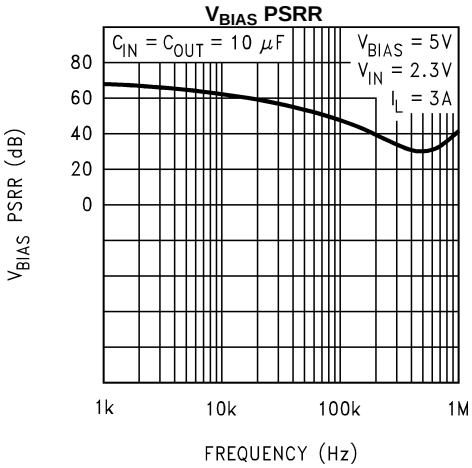

Figure 20.

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Application Hints

EXTERNAL CAPACITORS

To assure regulator stability, input and output capacitors are required as shown in the Typical Application Circuit.

OUTPUT CAPACITOR

At least 10µF of output capacitance is required for stability (the amount of capacitance can be increased without limit). The output capacitor must be located less than 1 cm from the output pin of the IC and returned to a clean analog ground. The ESR (equivalent series resistance) of the output capacitor must be within the "stable" range as shown in the graph below over the full operating temperature range for stable operation.

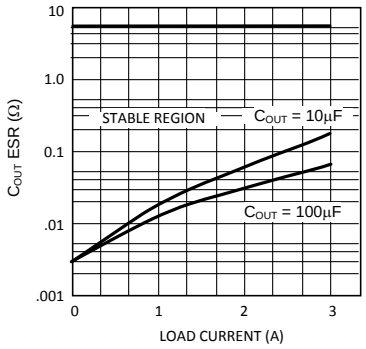

Figure 21. Minimum ESR vs Output Load Current

Tantalum capacitors are recommended for the output as their ESR is ideally suited to the part's requirements and the ESR is very stable over temperature. Aluminum electrolytics are not recommended because their ESR increases very rapidly at temperatures below 10°C. Aluminum caps can only be used in applications where lower temperature operation is not required.

A second problem with Al caps is that many have ESR's which are only specified at low frequencies. The typical loop bandwidth of a linear regulator is a few hundred kHz to several MHz. If an Al cap is used for the output cap, it must be one whose ESR is specified at a frequency of 100 kHz or more.

Because the ESR of ceramic capacitors is only a few milli Ohms, they are not suitable for use as output capacitors on LP389X devices. The regulator output can tolerate ceramic capacitance totaling up to 15% of the amount of Tantalum capacitance connected from the output to ground.

INPUT CAPACITOR

The input capacitor must be at least 10 µF, but can be increased without limit. It's purpose is to provide a low source impedance for the regulator input. Ceramic capacitors work best for this, but Tantalums are also very good. There is no ESR limitation on the input capacitor (the lower, the better). Aluminum electrolytics can be used, but their ESR increase very quickly at cold temperatures. They are not recommended for any application where temperatures go below about 10°C.

BIAS CAPACITOR

The 0.1µF capacitor on the bias line can be any good quality capacitor (ceramic is recommended).

BIAS VOLTAGE

The bias voltage is an external voltage rail required to get gate drive for the N-FET pass transistor. Bias voltage must be in the range of 4.5 - 6V to assure proper operation of the part.

UNDER VOLTAGE LOCKOUT

The bias voltage is monitored by a circuit which prevents the regulator output from turning on if the bias voltage is below approximately 4V.

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SHUTDOWN OPERATION

Pulling down the shutdown ($\overline{S/D}$) pin will turn-off the regulator. Pin $\overline{S/D}$ must be actively terminated through a pull-up resistor (10 kΩ to 100 kΩ) for a proper operation. If this pin is driven from a source that actively pulls high and low (such as a CMOS rail to rail comparator), the pull-up resistor is not required. This pin must be tied to Vin if not used.

POWER DISSIPATION/HEATSINKING

A heatsink may be required depending on the maximum power dissipation and maximum ambient temperature of the application. Under all possible conditions, the junction temperature must be within the range specified under operating conditions. The total power dissipation of the device is given by:

$$P_D = (V_{IN} - V_{OUT})I_{OUT} + (V_{IN})I_{GND} \quad (1)$$

where I_{GND} is the operating ground current of the device.

The maximum allowable temperature rise (T_{Rmax}) depends on the maximum ambient temperature (T_{Amax}) of the application, and the maximum allowable junction temperature (T_{Jmax}):

$$T_{Rmax} = T_{Jmax} - T_{Amax} \quad (2)$$

The maximum allowable value for junction to ambient Thermal Resistance, θ_{JA}, can be calculated using the formula:

$$\theta_{JA} = T_{Rmax} / P_D \quad (3)$$

These parts are available in TO-220 and DDPAK/TO-263 packages. The thermal resistance depends on amount of copper area or heat sink, and on air flow. If the maximum allowable value of θ_{JA} calculated above is ≥ 60°C/W for TO-220 package and ≥ 60°C/W for DDPAK/TO-263 package no heatsink is needed since the package can dissipate enough heat to satisfy these requirements. If the value for allowable θ_{JA} falls below these limits, a heat sink is required.

HEATSINKING TO-220 PACKAGE

The thermal resistance of a TO-220 package can be reduced by attaching it to a heat sink or a copper plane on a PC board. If a copper plane is to be used, the values of θ_{JA} will be same as shown in next section for DDPAK/TO-263 package.

The heatsink to be used in the application should have a heatsink to ambient thermal resistance,

$$\theta_{HA} \leq \theta_{JA} - \theta_{CH} - \theta_{JC}. \quad (4)$$

In this equation, θ_{CH} is the thermal resistance from the case to the surface of the heat sink and θ_{JC} is the thermal resistance from the junction to the surface of the case. θ_{JC} is about 3°C/W for a TO-220 package. The value for θ_{CH} depends on method of attachment, insulator, etc. θ_{CH} varies between 1.5°C/W to 2.5°C/W. If the exact value is unknown, 2°C/W can be assumed.

HEATSINKING DDPAK/TO-263 PACKAGE

The DDPAK/TO-263 package uses the copper plane on the PCB as a heatsink. The tab of these packages are soldered to the copper plane for heat sinking. The graph below shows a curve for the θ_{JA} of DDPAK/TO-263 package for different copper area sizes, using a typical PCB with 1 ounce copper and no solder mask over the copper area for heat sinking.

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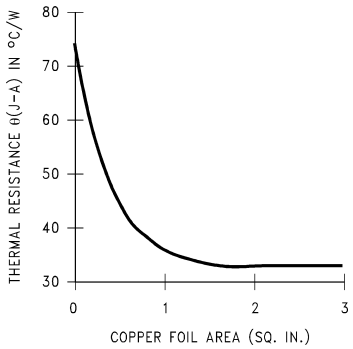

Figure 22. θ_{JA} vs Copper (1 Ounce) Area for DDPAK/TO-263 Package

As shown in the graph below, increasing the copper area beyond 1 square inch produces very little improvement. The minimum value for θ_{JA} for the DDPAK/TO-263 package mounted to a PCB is 32°C/W.

Figure 23 shows the maximum allowable power dissipation for DDPAK/TO-263 packages for different ambient temperatures, assuming θ_{JA} is 35°C/W and the maximum junction temperature is 125°C.

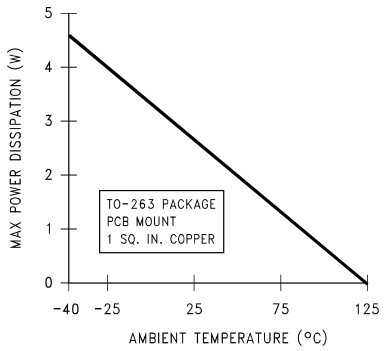

Figure 23. Maximum Power Dissipation vs Ambient Temperature for DDPAK/TO-263 Package

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REVISION HISTORY

Changes from Revision A (April 2013) to Revision B	Page
• Changed layout of National Data Sheet to TI format	9

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LP3893ES-1.2	NRND	DDPAK/ TO-263	KTT	5	45	Non-RoHS & Green	Call TI	Level-3-235C-168 HR	-40 to 125	LP3893ES -1.2	
LP3893ES-1.2/NOPB	ACTIVE	DDPAK/ TO-263	KTT	5	45	RoHS-Exempt & Green	SN	Level-3-245C-168 HR	-40 to 125	LP3893ES -1.2	Samples
LP3893ESX-1.2/NOPB	ACTIVE	DDPAK/ TO-263	KTT	5	500	RoHS-Exempt & Green	SN	Level-3-245C-168 HR	-40 to 125	LP3893ES -1.2	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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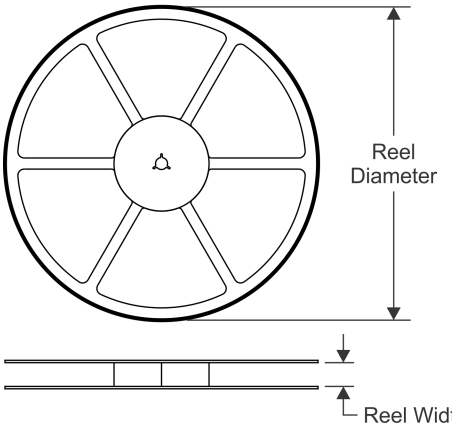
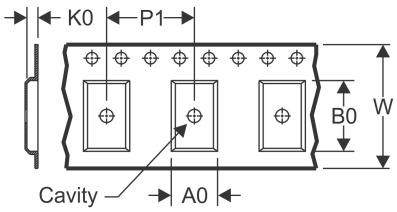
TAPE AND REEL INFORMATION

REEL DIMENSIONS

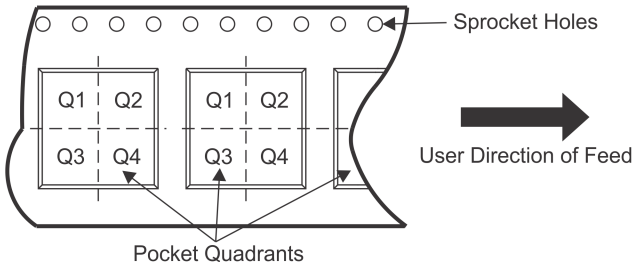


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

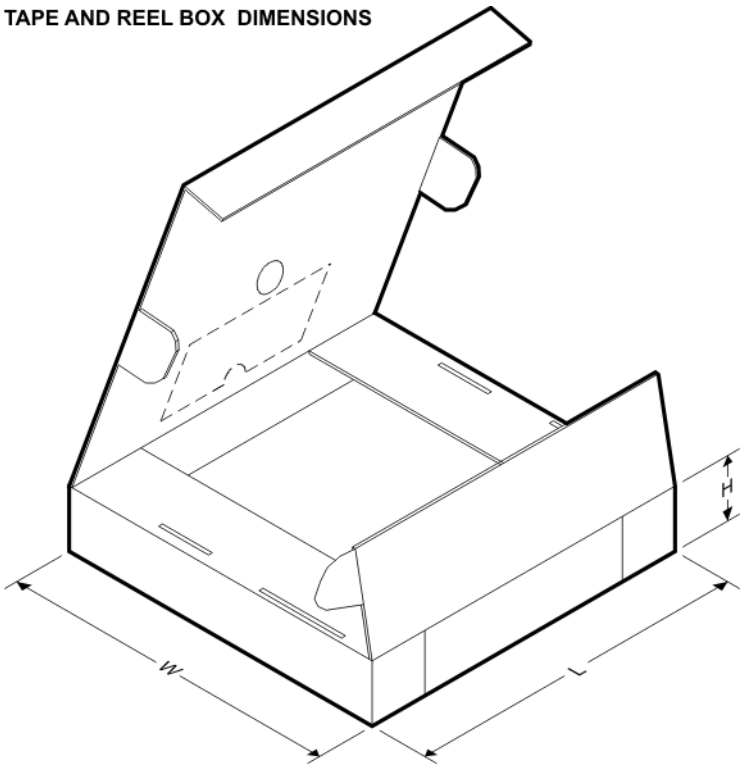
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LP3893ESX-1.2/NOPB	DDPAK/ TO-263	KTT	5	500	330.0	24.4	10.75	14.85	5.0	16.0	24.0	Q2

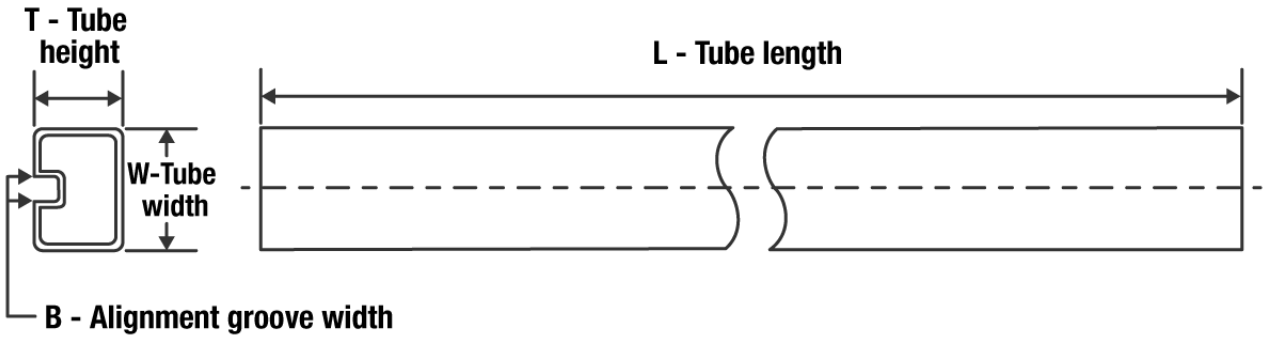
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LP3893ESX-1.2/NOPB	DDPAK/TO-263	KTT	5	500	367.0	367.0	45.0

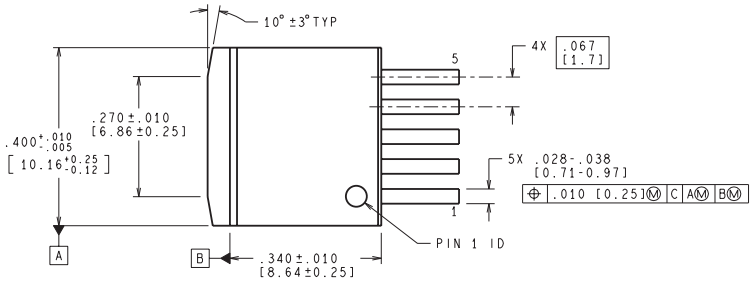
TUBE

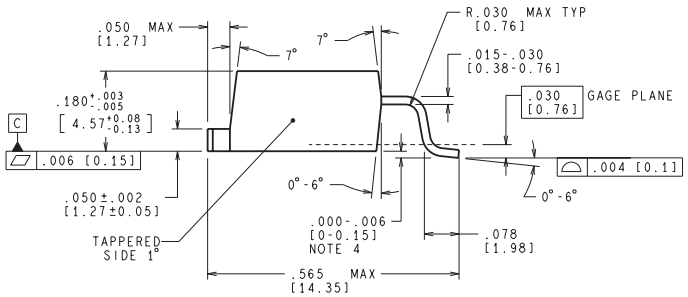


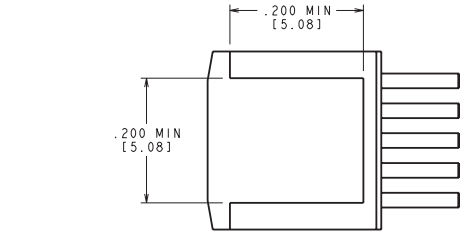
*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
LP3893ES-1.2	KTT	TO-263	5	45	502	25	8204.2	9.19
LP3893ES-1.2	KTT	TO-263	5	45	502	25	8204.2	9.19
LP3893ES-1.2/NOPB	KTT	TO-263	5	45	502	25	8204.2	9.19

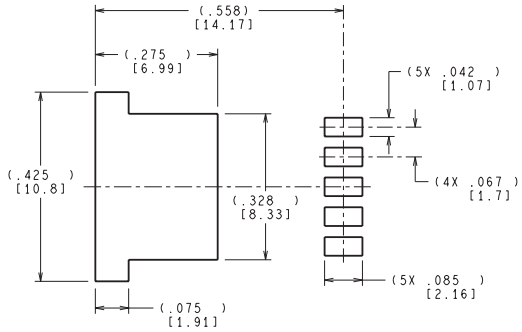
KTT0005B







BOTTOM SIDE OF PACKAGE



LAND PATTERN RECOMMENDATION

CONTROLLING DIMENSION IS INCH
VALUES IN [ ] ARE MILLIMETERS
DIMENSIONS IN ( ) FOR REFERENCE ONLY

TS5B (Rev D)

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